TINCH-POUND

MIL-S-19500/1928 6 October 1989 SUPERSEDING MIL-S-19500/192A 19 April 1968

### MILITARY SPECIFICATION

### SEMICONDUCTOR DEVICE, DIODE, GERMANIUM, SWITCHING TYPE 1N276, JAN, JANTX, AND JANTXY

This specification is approved for use by all Departments and Agencies of the Department of Defense.

### 1. SCOPE

- 1.1 Scope. This specification covers the detail requirements for a germanium semiconductor diode. Three levels of product assurance are provided for each device type as specified in MIL-S-19500.
  - 1.2 Physical dimensions. See figure 1 (DO-7).
  - 1.3 Maximum ratings.

Vr	l V <sub>rm</sub>	1 <sub>0</sub> 1/	1 <sub>f</sub>	if (surge)	Operating     ambient   temperature	T <sub>STG</sub>	Barometric     pressure
Y (pk)	   Y (pk)	mA dc	ma	1/120 second	°c	*ċ	l Imma∺Hg i
100	70	40	   150 	0.5	-65 to     +75	-65 to +100	8

- 1/ Derate Io linearly to 0.0 mA dc at +75°C.
- 1.4 Primary electrical characteristics. The diode shall have salient characteristics at ambient temperature of  $25 \text{ C} \pm 3 \text{ C}$ , unless otherwise specified.

آ ا ا	Υ <sub>F</sub>	IR	ir	IR
)   	IF = 40 mA dc	V <sub>R</sub> = 10 V dc	Y <sub>R</sub> = 100 Y(pk)	V <sub>R</sub> = 10 V dc T <sub>A</sub> = +75°C
Min				
Max	1.0 V dc	20 μΑ	800 mA (pk)	ا ل A dc لي 100 ل

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be lof use in improving this document should be addressed to: Commander, Defense Electronics Supply | Center, ATTN: DESC-ES, 1507 Wilmington Pike, Dayton, OK 45444-5276 by using the self-addressed | Standardization Document Proposal (DD Form 1426) appearing at the end of this document or by | letter.

- 2. APPLICABLE DOCUMENTS
- 2.1 Government documents.
- 2.1.1 Specifications, standards, and handbooks. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation (see 6.2).

SPECIFICATION

**MILITARY** 

MIL-S-19500 - Semiconductor Devices, General Specification for.

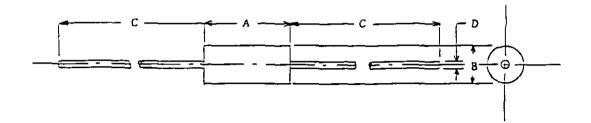
STANDARD

**MILITARY** 

MIL-STD-750 - Test Methods for Semiconductor Devices.

(Unless otherwise indicated, copies of federal and military specifications, standards, and handbooks are available from the Naval Publications and Forms Center, (ATTN: NPODS), 5801 Tabor Avenue, Philadelphia, PA 19120-5099.)

- 2.2 Order of precedence. In the event of a conflict between the text of this document and the references cited herein (except for related associated detail specifications, specification sheets, or MS standards), the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.
  - 3. REQUIREMENTS
- 3.1 Detail specification. The individual item requirements shall be in accordance with MIL-S-19500, and as specified herein.
- 3.2 Abbreviations, symbols, and definitions. Abbreviations, symbols, and definitions used herein shall be as specified in MIL-S-19500.
- 3.3 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-S-19500, and on figure 1.
- 3.3.1 <u>Lead material and finish</u>. Lead material shall be Dumet wire. Lead finish shall be tin plated or solder plated. Where a choice of lead material or finish is desired, it shall be specified in the contract or purchase order (see 6.2).
- 3.4 Marking. Marking shall be in accordance with MIL-S-19500. At the option of the manufacturer, the following marking may be omitted from the body of the diode.
  - a. Manufacturer's identification
  - b. Country of orgin
  - c. The "IN" portion of the type designation



Ltr		Dimens	ions	,	Notes
	Inches		Inches Millimeters		 
	Min	Max	Min	Max	j 1
Α	.230	.300	5.84	7.62	
В	.085	.130	2.16	3,30	44
С_	1.000	1.500	25.40	38.10	3
D	018	.022	l .46	1 1 .56	1, 2, and 3

## NOTES:

- The specified lead diameter applies in the zone between .050 (1.27 mm) and 1.000 (25,40 mm) from the diode body. Outside of this zone the lead diameter is not controlled.
- 2. Gold plated, tinned, or solder plated leads may be supplied providing units conform to subgroups 2 and 4 of group B inspection and subgroup 1 of group C inspection.
- 3. Both leads shall be within the specified dimension.
- 4. The minimum body diameter shall be maintained over .15 (0.38 mm) of body length.
- 5. Metric equivalents are given for general information only.

FIGURE 1. Semiconductor device, diode, type 1N276 (DO-7).

- 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection shall be in accordance with MIL-S-19500 and as specified herein.
  - 4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-S-19500.
- 4.3 Screening (JANTX and JANTXY levels only). Screening shall be in accordance with MIL-S-19500 (table II), and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.

Measurements						
Screen (see table II of MIL-S-19500)	JANTX and JANTXV levels					
3	  T <sub>A</sub> = maximum rated storage   temperature.					
10						
11	II <sub>R1</sub> and V <sub>F1</sub>					
12						
13						

4.3.1 Power burn-in conditions. Power burn-in conditions are as follows: All devices shall be operated at 25°C +3°C under one of the following conditions:

Condition 1: See 4.5.3

 $I_0 = 40 \text{ mA dc}$   $V_R = 70 \text{ V pk}$ 

Condition 2: IF = 40 mA dc

- 4.4 Quality conformance inspection. Quality conformance inspection shall be in accordance with MIL-S-19500.
- 4,4.1 Group A inspection. Group A inspection shall be conducted in accordance with MIL-S-19500, and table I herein. (End point electrical measurements shall be in accordance with the applicable steps of table IV herein.)
- 4.4.2 Group B inspection. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in table IVb of MIL-S-19500 and table IIb herein. Electrical measurements (end points) and delta requirements shall be in accordance with the applicable steps of table IV herein.
- 4.4.3 Group C inspection. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in table Y of MIL-S-19500, and table III herein. Electrical measurements (end points) and delta requirements shall be in accordance with the applicable steps of table IV herein.

TABLE I. Group A inspection.

Inspection 1/	1	MIL-STD-750	Symbol	Lir	nits	Unit
<u> </u>	  Method	Conditions		Min	   Max	
Subgroup 1 Visual and mechanical examination	2071			 	 	
Subgroup 2			l I		<u> </u>	
Forward voltage	4011	$I_F = 10$ mA dc (see 4.5.1)	V <sub>F1</sub>	   	0.5	V dc
Forward voltage	4011	$I_F = 40 \text{ mA dc (see 4.5.1)}$	V <sub>F2</sub>		1.0	V dc
Reverse current leakage	4016	V <sub>R</sub> = 10 V dc	I <sub>R1</sub>	İ	20	μA dc
Reverse current leakage	4016	$V_R = 50 \text{ V dc}$	I <sub>R2</sub>	i i	100	μA dc
Peak reverse voltage at peak reverse voltage		V <sub>r</sub> = 100 V (pk) AC method	f <sub>r</sub>	! 	  800   	μA (pk)
Reverse recovery time	     	Test condition B,  VR = 40 V dc,  IF = 5 mA dc,  RL = 2 kΩ,  C = 10 pF,  Recover to 100 kΩ	t <sub>rr</sub>	 	  300   	ns
  Forward recovery voltage	4026	I <sub>F</sub> = 50 V dc	V <sub>fr</sub>		3.0	V dc
  Capacitance 		V <sub>R</sub> = 1.5 V dc V <sub>R</sub> = 9 V dc	C1 C2	! 		pf pf
Subgroup 3	İ			į	į I	
  Reverse current leakage		TA = 75°C,	I <sub>R3</sub>	į	100	μA dc
	1	V <sub>R</sub> = 10 V dc, V <sub>R</sub> = 50 V dc, t = 60 seconds	ΔIR	   	10	μA dc
Subgroup 4					; ;	
  Not applicable	ļ			ļ	!	
Subgroup 5			 		į	
  Not applicable			   		j	i i
Subgroup 6			i	Ì	į	į
  Surge current   	1	$ I_0  = 40$ mA dc, $ i_f $ (surge) = 0.5 A, $ t_p  = 1/120$ seconds,  10  surges at 1 per minute		 	       	<b>]</b>   
  Electrical measurements 	   			!   	   	<b> </b> 

 $<sup>\</sup>underline{1}$ / For sampling plan, see MIL-S-19500.

TABLE IIb. Group B inspection for JAN, JANTX, and JANTXY.

Inspection 1/	MTL STD 750			
inspection 17	<del>                                     </del>	MIL-STD-750		
ļ	Method	Conditions		
Subgroup 1	ĺ	į		
Solderability	2026			
Resistance to solvents	1022			
Subgroup 2	 			
Thermal shock (temperature cycling)	1051			
  Hermetic seal   a. Fine leak   b. Gross leak	   1071   	i ITest condition H ITest condition E		
  Electrical measurements	<u>.</u>	See table IV, steps 1, 3, and 5.		
Subgroup 3	!   !			
Steady-state operation life	1027 	If = 60 Hz, I <sub>0</sub> = 40 mA dc, V <sub>r</sub> = 70 V (pk)   t = 340 hours, T <sub>A</sub> = 25°C, see 4.5.3.		
Electrical measurements		See table IV, steps 2, 3, and 4.		
Subgroup 4				
Decap internal visual (design verification)	2075			
Subgroup 5		Qualification only.		
Thermal resistance	4081			
<u>Subgroup 6</u>				
High temperature (nonoperating) life	1032	T <sub>A</sub> = 100°C		
Electrical measurements		See table IV, steps 2, 3, and 4.		

<sup>1/</sup> For sampling plan, see MIL-S-19500.

TABLE III. Group C inspection (all quality levels).

Inspection 1/		MIL-STD-750
	(  Method	
Subgroup 1		
  Physical dimensions	2066	
Subgroup 2	! !	
! !Thermal shock (glass strain) !	1056	Test condition A
  Terminal strength	2036	Test condition A, 4 pounds, t = 15 ±3 seconds
Hermetic seal a. Fine leak b. Gross leak	1071	
  Moisture resistance	1021	
  External visual	2071	
  Electrical measurements	¦ '	See table IV, steps 1, 3, and 5.
Subgroup 3	   	
Shock	2016	
  Yibration, variable   <i>frequency</i>	2056 	
  Constant acceleration	2006	
  Electrical measurements     <u>Subgroup 4</u>	     	  See table IV, steps 1, 3, and 5.   
  Salt atmosphere (corrosion)	1041	
Subgroup 5	    -	
  Not applicable 	]   	
Subgroup 6	i I	
	1026	f = 60 Hz, T <sub>A</sub> = 25°C, I <sub>O</sub> = 40 mA dc,  V <sub>r</sub> at 70 V pk, t = 1,000 hours, see 4.5.3.
Electrical measurements		See table IV, steps 2, 3, and 4.

 $<sup>\</sup>underline{1}/$  For sampling plan, see MIL-S-19500.

TABLE IV. Groups A, B, and C electrical measurements.

Step	Inspection	<u> </u>	MIL-STD-750	Symbol	Limits		   Unit
		Method	Conditions		Min	l l Max	<u> </u>
1.	Reverse current   leakage	4016	   Y <sub>R</sub> = 10 V dc 	IRL		20	Π I μA dc I
2.	! Reverse current ! leakage	4016	   V <sub>R</sub> = 10 V dc 	I R2		100	l μΑ dc l
3.	   Forward voltage 	4011	l IF≖40 mAdc I	Y <sub>F2</sub>		1.0	l V dc
4.	   Reverse current   leakage	4016	   V <sub>R</sub> = 50 V dc	I I <sub>R4</sub>		150	i IμΑdc I
5.	   Reverse current   leakage	4016	V <sub>R</sub> = 50 V dc	I <sub>R3</sub>		100	l μA dc

- 4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows:
- 4.5.1 Pulse measurements. Conditions for pulse measurements shall be as specified in section 4 of MIL-STD-750.
- 4.5.2 Time limit for end points. End points for qualification and quality conformance inspection shall be completed within 96 hours after completion of the last test in the subgroup.
- 4.5.3 Power burn-in criteria. This test shall be conducted with a half-sine wave of the specified peak voltage impressed across the diode in the reverse direction followed by a half-sine waveform of the specified average rectified current. The forward conduction angle of the rectified current shall be not greater than 180 nor less than 130, and the power shall be equal to or greater than that of a half-sine wave.

## 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-S-19500.

### 6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

- 6.1 Notes. The notes specified in MIL-S-19500 are applicable to this specification.
- 6.2 Acquisition requirements. Acquisition documents must specify the following:
  - a. Title, number, and date of the specification.
  - b. Issue of DODISS to be cited in the solicitation, and if required, the specific issue of individual documents referenced (see 2.1).
  - c. Lead finish may be specified (see 3.3.1).
- 6.3 <u>Substitution information</u>. Devices covered by this specification are substitutable for the manufacturers' and users' Part or Identifying Number (PIN). This information in no way implies that manufacturers' PIN's are suitable as a substitute for the military PIN.

Military PIN	Manufacturers'   CAGE code	Manufacturers' and users   PIN
	l !	] 
	1	]
	! 	!   
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	! [	
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## MIL-S-19500/1928

6.4 Changes from previous issue. Marginal notations are not used in this revision to identify changes with respect to the previous issue due to the extensiveness of the changes.

## CONCLUDING MATERIAL

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Review activities:

Army - AR Air Force - 17, 85 Navy - SH DLA - ES

User activities:

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